COMPLIANT

HALOGEN FREE

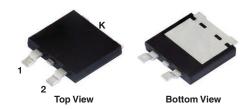


Vishay General Semiconductor

Dual High-Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low $V_F = 0.48 \text{ V}$ at $I_F = 5.0 \text{ A}$

eSMP[®] Series SMPD (TO-263AC)





LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 10 A			
V_{RRM}	100 V			
I _{FSM}	130 A			
V _F at I _F = 10 A (T _J = 125 °C)	0.59 V			
T _J max.	150 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V20D103C	UNIT	
Device marking code			V20D103C		
Maximum repetitive peak reverse voltage		V _{RRM}	100	V	
Maximum average forward rectified current (fig. 1)	per device	I (1)	20	Α	
	per diode	I _{F(AV)} ⁽¹⁾	10	7	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I _{FSM}	130	А	
Operating junction temperature range		T _J ⁽²⁾	-40 to +150	°C	
Storage temperature range		T _{STG}	-55 to +150]	

Notes

- (1) Mounted on infinite heatsink
- $^{(2)}$ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$



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ELECTRICAL CHARACTERISTICS (T _J = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 5 A	T _J = 25 °C	- V _F ⁽¹⁾	0.54	-	V
	I _F = 10 A			0.66	0.75	
	I _F = 5 A	T _J = 125 °C		0.48	-	
	I _F = 10 A			0.59	0.67	
Reverse current at rated V _R per diode	V _R = 70 V	T _J = 25 °C	I _R ⁽²⁾	0.003	-	mA
		T _J = 125 °C		3	-	
	V _R = 100 V	T _J = 25 °C		-	0.49	
		T _J = 125 °C		7	24	
Typical junction capacitance	4.0 V, 1 MHz		CJ	1000	-	pF

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL V20D103C		UNIT	
Typical thermal resistance per device	R _{θJC} ⁽¹⁾	1.8	°C/W	
	R _{0JA} (2)(3)	58	C/VV	

Notes

- (1) Mounted on infinite heatsink
- (2) The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta,JA}$
- (3) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V20D103C-M3/I	0.55	1	2000/reel	13" diameter plastic tape and reel		
V20D103CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

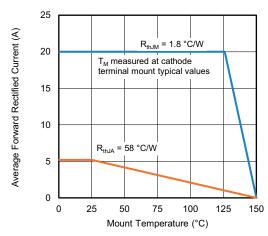


Fig. 1 - Maximum Forward Current Derating Curve

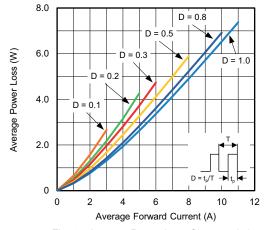


Fig. 2 - Average Power Loss Characteristics



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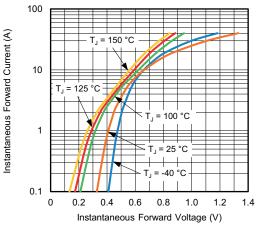


Fig. 3 - Typical Instantaneous Forward Characteristics

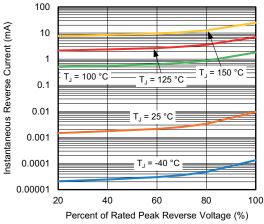


Fig. 4 - Typical Reverse Leakage Characteristics

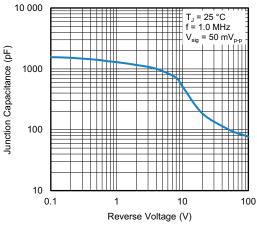


Fig. 5 - Typical Junction Capacitance

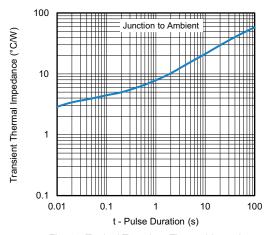


Fig. 6 - Typical Transient Thermal Impedance

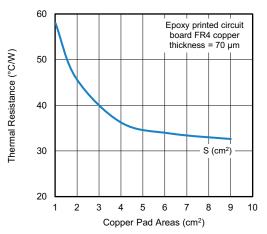
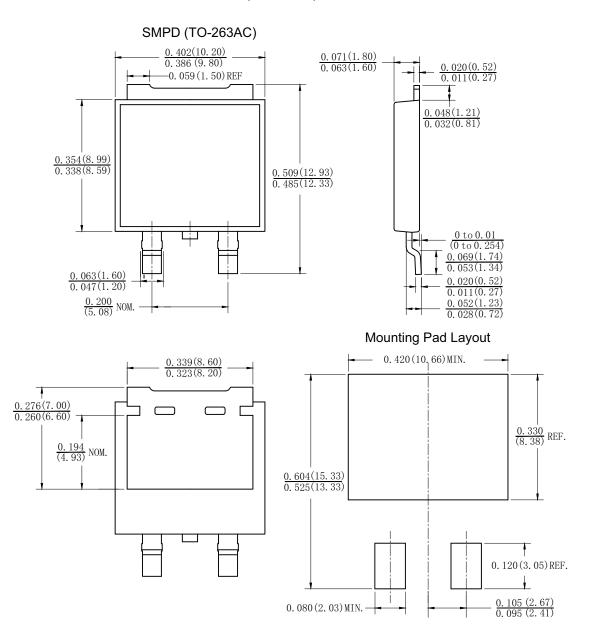


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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